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1141.	CITATION	I IN AN	APPLICANT Frederic NGUYEN VAN DAU						
APPLICATION (PTO-1449)				FILING DATE herewith		GROUP 2826			
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; fraw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.